NSN 5961-01-411-0312

Demilitarization:

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-411-0312 **Inclosure Material:** Plastic **Overall Length:** 3.0 millimeters **Overall Height:** 1.1 millimeters **Overall Width:** 2.5 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-143 **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 70.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 1.00 amperes source cutoff current absolute all semiconductor device diode **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Test Data Document:** 30003-2037as362 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 printed circuit Shelf Life: N/a **Unit Of Measure:**